

## **Description**

The AO9926C uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.



SOP-8

#### **General Features**

 $V_{DS} = 20V I_{D} = 8 A$ 

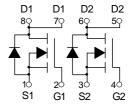
 $R_{DS(ON)} < 20m\Omega$  @  $V_{GS}$ =4.5V

## **Application**

Battery protection

Load switch

Uninterruptible power supply



**Dual N-Channel MOSFET** 

## **Package Marking and Ordering Information**

Product ID	Pack	Brand	Qty(PCS)
AO9926C	SOP-8	HXY MOSFET	3000

## Absolute Maximum Ratings (Tc=25℃unless otherwise noted)

Symbol	Parameter	Limit	Unit
V <sub>DS</sub>	Drain-Source Voltage	20	V
V <sub>G</sub> S	Gate-Source Voltage	±12	V
I <sub>D</sub>	Drain Current-Continuous	8	Α
Ірм	Pulsed Drain Current	28	А
P <sub>D</sub>	Maximum Power Dissipation	2.25	W
T <sub>J</sub> ,T <sub>STG</sub>	Operating Junction and Storage Temperature Range	-55 To 150	$^{\circ}$ C
Rejc	Thermal Resistance,Junction-to-Case <sup>(Note 2)</sup>	80	°C/W



# Electrical Characteristics (T<sub>J</sub>=25°C unless otherwise noted)

Parameter	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	$V_{GS} = 0V, I_D = 250\mu A$	20	-	-	V
Gate Leakage Current	lgss	V <sub>GS</sub> = ±12V, V <sub>DS</sub> = 0V	-	-	±100	nA
Drain Cut-off Current	IDSS	V <sub>DS</sub> = 20V, V <sub>GS</sub> = 0V	-	-	1	μA
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>GS</sub> = V <sub>DS</sub> , I <sub>D</sub> = 250μA	0.45	0.7	1	٧
Drain-Source On-State Resistance <sup>3</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = 4.5V, I <sub>D</sub> =5A	-	13	20	mΩ
		V <sub>GS</sub> = 2.5V, I <sub>D</sub> = 4.7A	-	18	30	
		V <sub>GS</sub> = 1.8V, I <sub>D</sub> = 4.3A	-	28	57	
Dynamic Characteristics <sup>4</sup>						
Input Capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V, V <sub>DS</sub> = 10V, f = 1MHz	-	700	-	pF
Output Capacitance	C <sub>oss</sub>		-	120	-	
Reverse Transfer Capacitance	Crss		-	105	-	
Switching Characteristics <sup>4</sup>						
Total Gate Charge	Qg		-	10.5	-	nC
Gate-Source Charge	Qgs	V <sub>GS</sub> = 4.5V, V <sub>DS</sub> = 10V, I <sub>D</sub> = 5A	-	2	-	
Gate-Drain Charge	Q <sub>gd</sub>		-	2.5	-	
Turn-On Time	t <sub>d(on)</sub>	$V_{GS}$ = 5V, $V_{DD}$ = 10V, $I_D$ = 5A, $R_G$ = 3 $\Omega$ ,	-	10	-	ns
Rise Time	t <sub>r</sub>		-	20	-	
Turn-Off Time	t <sub>d(off)</sub>		-	32	-	
Fall Time	tf		-	12	-	
Source-Drain Diode Characteristics						
Body Diode Voltage <sup>3</sup>	V <sub>SD</sub>	I <sub>S</sub> =4A, V <sub>GS</sub> = 0V	-	-	1.2	V
Continuous Source Current	Is		-	-	8	Α

#### Notes:

- 1. Repetitive rating, pulse width limited by junction temperature  $T_{\text{J(MAX)}}\text{=}150^{\circ}\text{C}.$
- 2. The data tested by surface mounted on a 1 inch2 FR-4 board with 2OZ copper, The value in any given application depends on the user's specific board design.
- 3. Pulse Test: Pulse width≤300µs, duty cycle≤2%.
- 4. This value is guaranteed by design hence it is not included in the production test.



## **Typical Characteristics**

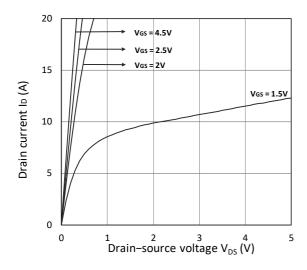


Figure 1. Output Characteristics

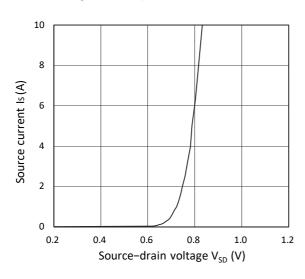


Figure 3. Forward Characteristics of Reverse

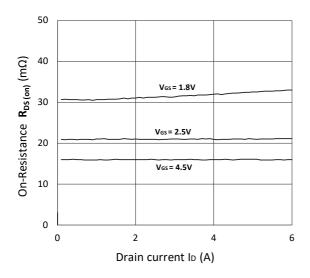


Figure 5.  $R_{DS(ON)}$  vs.  $I_D$ 

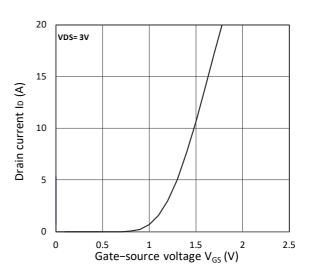


Figure 2. Transfer Characteristics

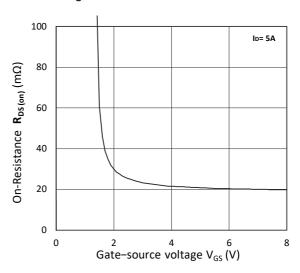


Figure 4.  $R_{DS(ON)}$  vs.  $V_{GS}$ 

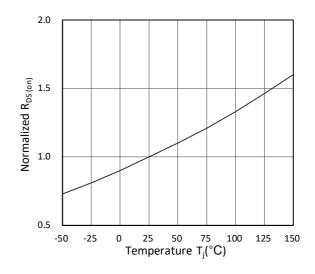
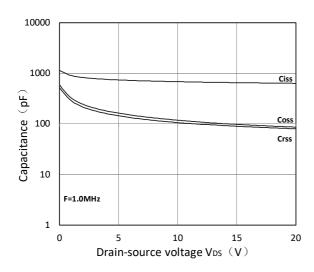


Figure 6. Normalized  $R_{\text{DS(on)}}$  vs. Temperature





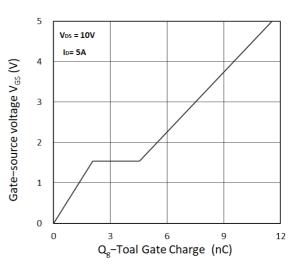
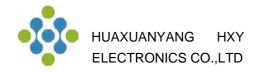
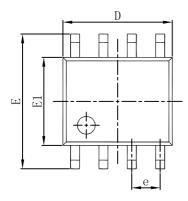
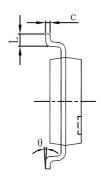


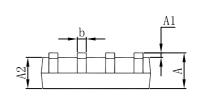
Figure 8. Gate Charge Characteristics



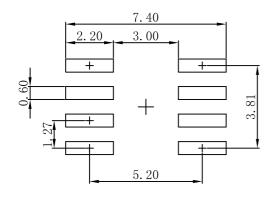
# **SOP-8 Package Outline Dimensions**







Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
A	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
c	0.170	0.250	0.007	0.010	
D	4.800	5.000	0.189	0. 197	
e	1.270 (BSC)		0.050 (BSC)		
E	5.800	6. 200	0.228	0.244	
E1	3.800	4.000	0.150	0.157	
L	0.400	1.270	0.016	0.050	
θ	0°	8°	0°	8°	



- Note: 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.
  3.The pad layout is for reference purposes only.



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